

DCR1460F30

Phase Control Thyristor

DS6046-2 June 2019 (LN38866)

KEY PARAMETERS

FEATURES

APPLICATIONS

.

- Double Side Cooling
- High Surge Capability

High Power Drives

Static Switches

VOLTAGE RATINGS

Part and Ordering

Number

DCR1460F30

DCR1460F28

DCR1460F26

DCR1460F24

High Voltage Power Supplies

Repetitive Peak

Voltages

V_{DRM} and V_{RRM} V

> 3000 2800

> 2600

2400

Conditions

 $T_{vj} = -40^{\circ}C$ to 125°C,

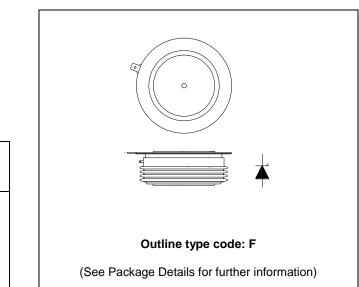
 $I_{DRM} = I_{RRM} = 150 \text{mA},$

 $V_{DSM} \& V_{RSM} =$ $V_{DRM} \& V_{RRM} +100V$ respectively

 V_{DRM} , V_{RRM} $t_p = 10ms$,

	3000 V
I _{T(AV)}	1460 A
ITSM	23000 A
dV/dt*	1000 V/µs
dl/dt	150 A/µs

* Higher dV/dt selections available



Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR1460F30

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.





CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Sid	de Cooled			
I _{T(AV)}	Mean on-state current	Half wave resistive load	1460	А
I _{T(RMS)}	RMS value	-	2290	А
Ι _Τ	Continuous (direct) on-state current	-	2060	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{TSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	23.0	kA
l ² t	I ² t for fusing	V _R = 0	2.65	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	5	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.02	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.005	°C/W
T _{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-	125	°C
T _{stg}	Storage temperature range			-40	140	°C
Fm	Clamping force			18	26	kN

DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditio	ins	Min.	Max.	Units
I _{RRM} /I _{DRM}	Peak reverse and off-state current	At V _{RRM} /V _{DRM} , T _{case} = 125°C		-	150	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, gate open		1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V _{DRM} to 2000A	Repetitive 50Hz	-	150	A/µs
		Gate source $30V$, 10Ω ,	Non-repetitive	-	1000	A/µs
		$t_r < 0.5 \mu s, T_j = 125^{\circ}C$				
VT	On-state voltage	I _T = 1500A, T _{case} = 125°C			1.40	V
V _{T(TO)}	Threshold voltage	T _{case} = 125°C		-	0.95	V
r _T	On-state slope resistance	T _{case} = 125°C		-	0.30	mΩ
t _{gd}	Delay time	$V_D = 67\% V_{DRM}$, gate source	30V, 10Ω	-	3.0	μs
		$t_r=0.5\mu s, T_j=25^\circ C$				
tq	Turn-off time	$T_j = 125^{\circ}C, V_R = 100V, dl/dt$	= 10A/µs,	-	300	μs
		$dV_{DR}/dt = 20V/\mu s$ linear to 67	7% V _{DRM}			
Qs	Stored charge	I _T = 2000A, tp = 1000us,T _j = 125°C, dl/dt =10A/μs,		-	3600	μC
I _{RR}	Reverse recovery current			-	165	А
١L	Latching current	$T_j = 25^{\circ}C,$		-	1	А
Ι _Η	Holding current	T _j = 25°C,		-	200	mA

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V _{GT}	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	3	V
V_{GD}	Gate non-trigger voltage	At 40% V _{DRM} , T _{case} = 125°C	0.3	V
I _{GT}	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	300	mA
I _{GD}	Gate non-trigger current	At 40% V _{DRM,} T _{case} = 125°C	20	mA

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CURVES

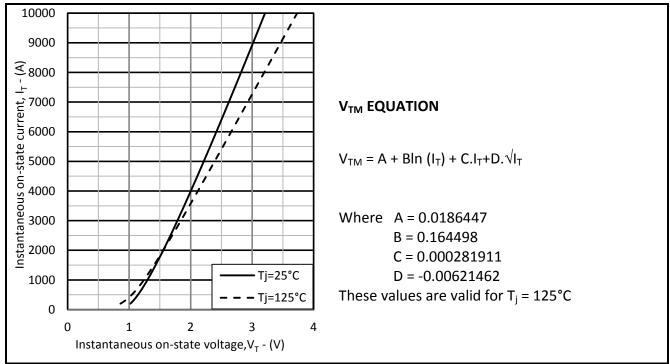


Fig.2 Maximum & minimum on-state characteristics

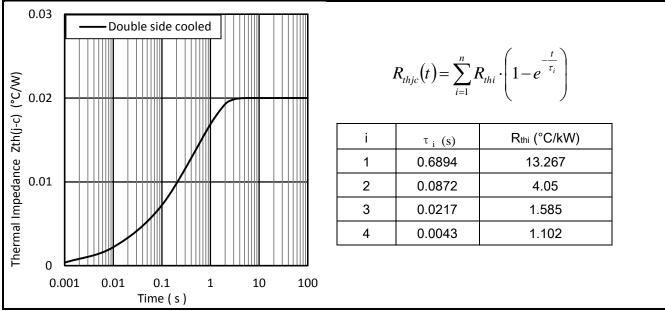
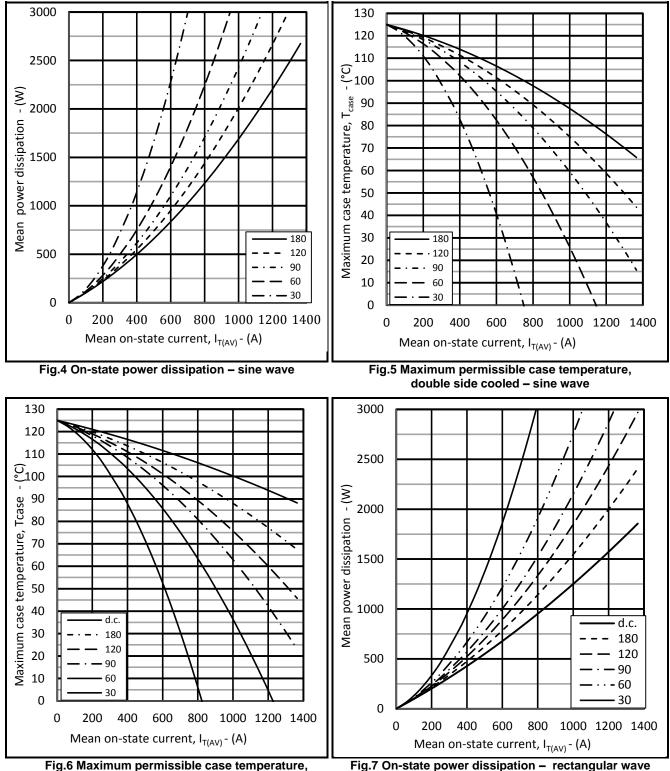
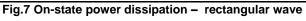


Fig.3 Maximum (limit) transient thermal impedance - junction to case (°C/W)



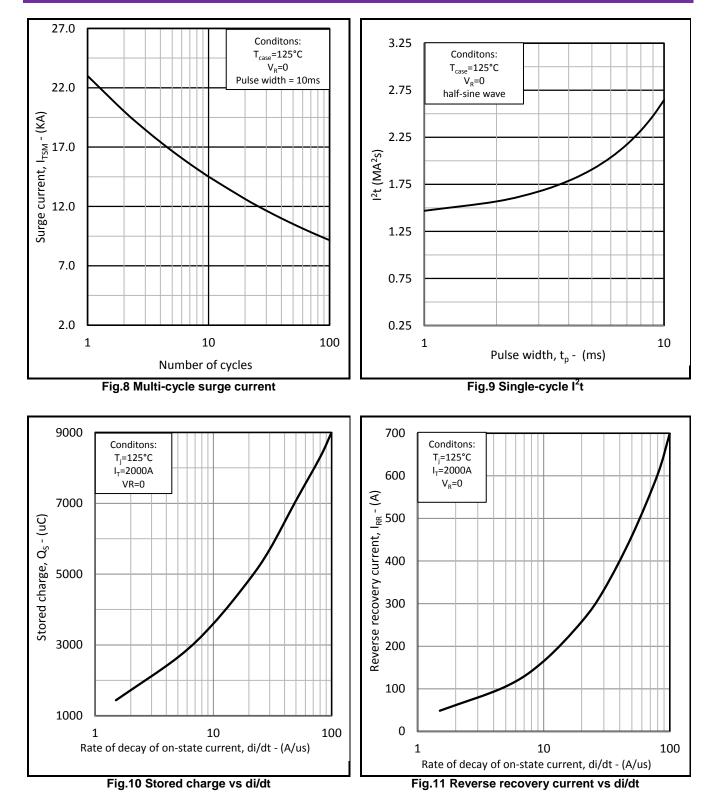


double side cooled - rectangular wave





DCR1460F30



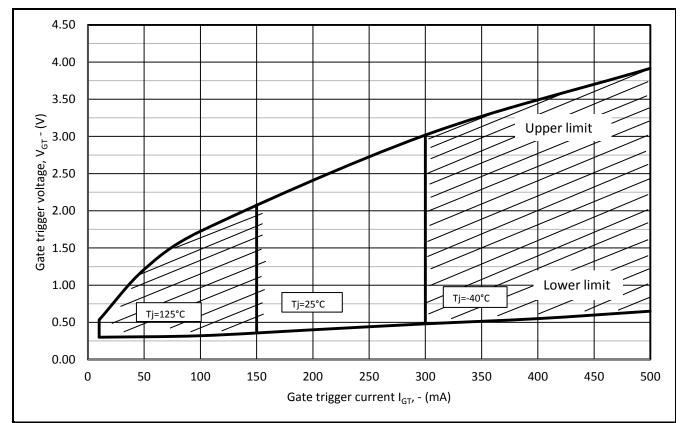


Fig.12 Gate characteristics

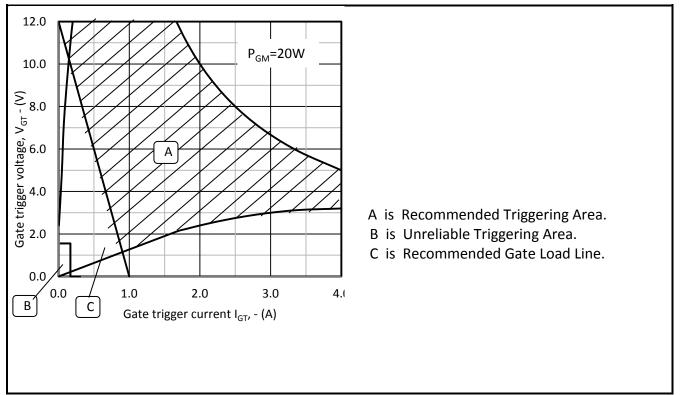


Fig.13 Gate characteristics

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PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

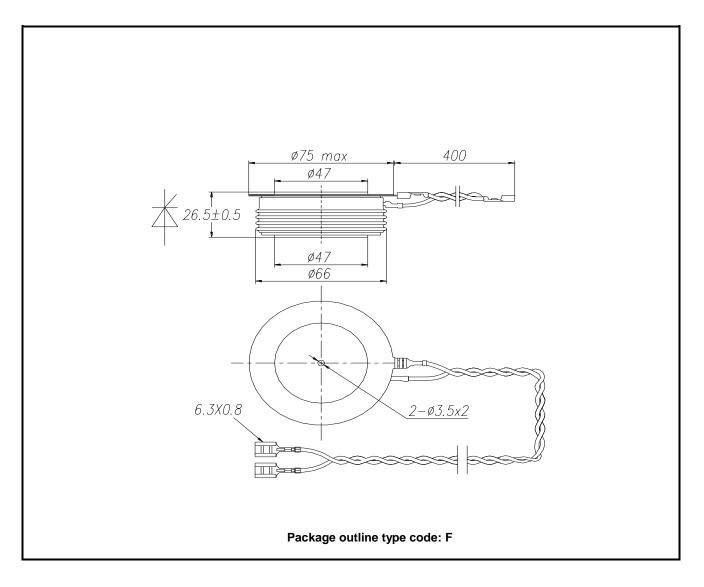


Fig.14 Package outline



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